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THE SYNGENETIC INCORPORATION OF ZINC IN THE LATTICE OF TUNGSTEN MOLYBDATE (ZN_XWMO₃) FOR POTENTIAL PHOTOVOLTAIC APPLICATION

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Abstract

This study highlights Zn-doped tungsten-molybdenum oxide (WMo₃) as a significant and promising new material in photovoltaics. The global demand for renewable energy is pushing the development of affordable, reliable, and high-performing materials. Films were deposited using a three-electrode electrochemical technique. The films' photovoltaic parameters were characterized. Fill factor measurements showed that the solar cell's quality improved from 51% (WMo₃) to 59% (Zn_{0.03}WMo₃). In other words, increased fill factors lead to improved solar cell efficiency and reduced voltage drops in circuits. A significant efficiency improvement is observed—a rise from 1.8% in WMo₃ to 6.3% in Zn_{0.03}WMo₃. Zinc doping improves the cell's efficiency in converting sunlight into electricity. Undoped WMO3 showed a uniform granular morphology with relatively smooth surfaces. The grains were wellcrystallized and tightly packed, but the surface area may be low. The structure's small size decreases porosity and surface roughness, limiting light trapping and charge transport. Introducing Zn modifies the morphology, leading to larger grains and increased surface porosity. Enhanced intergranular connectivity facilitated greater charge transport; rising zinc concentration induced peak intensity shifts and alterations, signifying amplified crystal lattice distortion. Enhanced properties, such as improved charge carrier mobility, make this material better for photovoltaic applications. Zn doping raises the bandgap from 1.27 eV in WMO₃ to 1.66 eV in Zn_{0.03}WMO₃. This shifted the optical absorption edge toward shorter wavelengths (from the near infrared region (NIR) to visible light), thus enhancing visible-light harvesting in photovoltaics.

1.0 INTRODUCTION

An energy crisis is among the world's most pressing problems. Inefficient energy use leads to economic weakness, higher inflation, and state instability. Scientists worldwide are searching for abundant, renewable energy sources to mitigate the energy crisis and safeguard the environment. Scientists are searching for greener, sustainable energy sources [1], in contrast to traditional options, which are rapidly consuming resources and causing pollution. Solar energy is the most efficient of sustainable technologies, including hydropower, tidal power, biomass, and thermal [2]. With its abundance and renewability, solar energy could significantly contribute to meeting the world's future energy needs [3], [4].

Tungsten oxide (WO₃), a versatile n-type semiconductor with a wide band gap, has an array of *Vol. 44, No. 4, December, 2025*

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applications. Its unique electronic characteristics allow for novel functionalities, thus explaining its appeal. Using WO3 nanostructures (nanoparticles, nanorods, nanoplates, and nanowires) electrochromic devices, photocatalysis, gas sensing, and photovoltaic systems is widely explored due to their promising performance [5] [6], [7]. The transition metal oxides tungsten trioxide (WO3) and molvbdenum trioxide (MoO_3) have considerable attention in photovoltaics because of their distinctive electronic and optical characteristics. The alloving of tungsten and molybdenum oxides (WMo₃) shows promise for photovoltaic applications, exceeding the potential of the individual materials. Both WO_3 and MoO₃ are wide-bandgap semiconductors. Their wide band gaps suit them for transparent conducting oxides and hole transport layers within photovoltaic cells [8], [9]. Tunable electronic properties resulting from the combination of these oxides enable optimized charge transport and energy level alignment in solar cell structures. WO₃ and MoO₃ find use in photovoltaic applications as buffer, hole transport, or electron transport layers, contingent on the specific device design [10], [11]. Their high work functions enable efficient hole extraction, thus improving solar cell power conversion efficiency. Their ambient stability further contributes to the long life of photovoltaic devices. Combining WO3 and MoO3 to make WMo3 may unite the best qualities of each oxide. This results in better charge carrier mobility, increased visible light absorption, and improved energy level matching within solar cells. Improved device performance and stability may result from these synergistic effects [1], [9], [10], [12]. The application of WO3 and MoO3 in DSSCs, perovskite solar cells, and organic photovoltaics has been a focus of recent photovoltaic studies. Specifically, WO₃-based DSSCs have shown potential in solar energy conversion due to their promising efficiency and stability. In a similar vein, the use of MoO₃ as a hole transport layer in perovskite solar cells has been explored, resulting in better device performance. Investigating WMo3 alloys is the next logical step in this research. It combines the advantages of above mentioned oxides. WMo3 materials are only beginning to be developed for photovoltaic applications [6], [13]. **Improved** devices—efficient, photovoltaic stable, affordable-could arise from advancements in this field, furthering solar energy's acceptance.

While other methods for WMo₃ synthesis exist from past research, electrodeposition remains unutilized [14], [15]. This method is favored over others because

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of its scalability, affordability, wide area applicability, and precise composition control [15], [16], [17], [18]. The electrodeposition process involves four key stages: attraction of electrolyte cations to the cathode. conversion of cations to neutral atoms, diffusion and attachment of atoms to the cathode, formation of elements, alloys, or compound nuclei through reactions [19], [20], [21], [22], [23], [24], [25], [26]. Grains of these elements, alloys, or nuclei accumulate on the cathode, forming a film. Electrodeposition is affected by many factors such as current density, deposition time, electrolyte concentration, pH, and additives [27], [28], [29]. Substrate selection significantly impacts catalyst efficiency due to variations in catalyst growth patterns across different substrates.

Zn-doped tungsten-molybdenum oxide (WMo₃) is a significant and promising new material photovoltaic applications. The rising global need for renewable energy is driving the search for affordable, reliable, and high-performing materials. The oxide composite WMo₃, a blend of tungsten trioxide (WO₃) and molybdenum trioxide (MoO₃), boasts high thermal stability, an appropriate bandgap, and excellent conductivity. Targeted elemental doping can further enhance its performance [16], [17], [17]. Zinc ions in the WMo3 lattice in this case cause controlled defects and alter the electronic structure, thus enabling manipulation of the material's properties. Zinc, a small divalent metal ion, readily substitutes for W⁶⁺ or Mo⁶⁺ or occupies interstitial sites in the oxide matrix [18]. This substitution significantly impacts the bandgap, enhances charge carrier mobility, and minimizes recombination losses, which are crucial for high photovoltaic efficiency. Zn doping in other transition metal oxides has been shown to improve visible light absorption and energy level alignment photoactive layers. Zn-doped WMo3 is expected to absorb solar radiation more efficiently and facilitate faster, more directional transport of photogenerated charge carriers [18]-[20]. Besides this, zinc can enhance WMo3's surface morphology and porosity, leading to a larger surface area and improved photon interaction [21]-[24]. Integrating Zn into WMo₃ strategically adjusts its structure, optics, and electronics, resulting in a versatile material ideal for advanced solar cells.

The syngenetic integration of zinc (Zn) into the tungsten molybdate (WMo₃) lattice is still mainly unexplored, despite the growing interest in creating multifunctional metal molybdates for optoelectronic and photovoltaic applications. No published research has been done on the syngenetic production of ZnxWMo₃ compounds. The crystal structure, phase development, and comprehensive structural characterization of Zn-incorporated WMo₃ are thus still unresolved. Also missing from the research on WMo₃ is the effect of Zn inclusion on optical absorption properties and power conversion efficiency (PCE).

This study investigates potential photovoltaic applications of zinc-incorporated tungsten molybdate (ZnxWMo₃). The deposited films had their photovoltaic parameters characterized.

2.0 EXPERIMENTAL DETAILS

2.1 Materials Required

The synthesis of tungsten trioxide (WO₃) was carriedout using different precursors and reagents, which are: Ammonium tungstate (NH₄)₂[WO₄]·H₂O, ammonium Molvbdate $(NH_4)_2[MoO_4]\cdot H_2O$, Zinc (C₄H₆O₄Zn), distilled water, and HCl, conductive materials-fluorine doped tin oxide (FTO), Threeelectrode setup (working electrode, graphite electrode, Saturated calomel electrode (SCE) as reference electrode), Voltage regulator (-0.6 V to -1.0 V vs. SCE) and a controlled current density (1-10 mA/cm²). The reaction bath, distilled water, was mixed using a magnetic stirrer. Using a DC power supply, an electric field was established between a conducting glass cathode and a copper anode. Homogeneous film deposition was finally achieved via electrochemical deposition.

Current was applied to reduce tungsten and molybdenum ions, thus forming WMo₃. The reaction can be depicted as follows:

$$W^{6+} + Mo^{6+} + 3^{e-} \rightarrow WMo_3$$
 (1)

To produce zinc-doped WMo₃, a current was applied to reduce the metal ions. The overall reaction is illustrated as:

$$W^{6+} + Mo^{6+} + Zn^{2+} + 3^{e-} \rightarrow Zn_xWMo_3$$
 (2)

2.2 Electrolyte Solution Preparation And Subsequent Deposition.

molybdenum Tungsten oxide (WMo_3) is electrochemically synthesized through a chemical reaction in an electrochemical cell. This process uses electricity trigger chemical reactions to electrochemical cells. The cell, immersed electrolyte solution, uses electrodes (anode and

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cathode) and applied voltage/current to produce the reaction. Ultrasonic cleaning with ethanol, acetone, and distilled water (DM) thoroughly cleaned the 2.5 cm × 1.5 cm FTO substrate. 100 ml of DM received 0.1 M ammonium tungstate, 0.1 M oxide salt, and 0.01- 0.03 M zinc salt, with HCL drops added to 100ml of the DM to improve deposition. A three-electrode setup, including a working electrode (FTO), a graphite electrode, and a saturated calomel reference electrode (SCE), was employed, with the working electrode functioning as the cathode in Figure 1a.

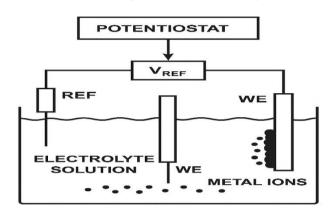


Figure 1a: Electrochemical deposition system (ECD).

WE (Working Electrode): where deposition occurs. CE (Counter Electrode): completes the current circuit.

RE (**Reference Electrode**): provides a stable referencevoltage (Ag/AgCl).

Potentiostat: controls the potential between the WE and RE and measures current between WE and CE. **Electrolyte Solution**: Contains the metal ions to be

deposited.

Vertically oriented, FTO-coated substrates, holding the counter and reference electrodes, filled the chambers during each deposition. After deposition, the films were cleaned and dried using a hand dryer. In the deposition process, 20 ml of ammonium tungstate (NH₄)₂[WO₄]·H₂O and ammonium molybdate (NH₄)₂[MoO₄]·H₂O, solutions (equal amounts), along with 5 ml of zinc acetate ($C_4H_6O_4Zn$) solution, were added to the beakers containing the target materials. To eliminate internal stress, samples were annealed for 30 minutes following deposition. A constant 10V was applied across the electrodes. A thorough analysis of the synthesized materials' optical, structural, elemental, and electrical properties was conducted using specialized tools and mathematical

models. Absorbance was measured from 300 to 1100 nm using a model 756s UV-Vis spectrophotometer. structural analysis employed an diffractometer, model Cu-Kal, with $\lambda = 1.15418 \ \hat{A}$. Using this method gives detailed information on crystal lattice properties, the intensities of diffraction peaks, and the crystal structures of natural and synthetic materials. The Model 16S-300-1.2-UV Advanced solar simulator enabled the measurement of characteristics under 950 mW/cm² PSC J-V illumination in a 4.0 cm² area in Figure 1b. Using the test cell holder, each PSC was wired to the solar simulator's positive and negative terminals. The JEOL JSM 6360 SEM provided morphology data, and EDX analysis provided chemical composition data. The film's thickness measured was surfacing/thicknessing mortise machine. A vintage Jandel four-point probe was used to determine the electrical properties of the synthesized materials.

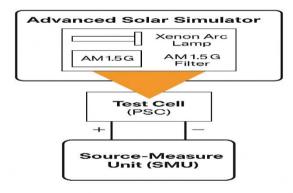


Figure 1b: Schematic diagram of an advanced solar simulator.

3.0 RESULTS AND DISCUSSIONS

3.1 The Photovoltaic Performance of WMo_3 and Zn_xWMo_3

The cells produce more current with the addition of zinc. WMo $_3$ yields 7 mA/

cm²while Zn_{0.01}WMo₃ generates 11 mA/cm², and this trend continues

with Zno.02WMo3 and Zno.03WMo3 producing 14 and 17 mA/cm², respectively, as shown in Table 1. This rise shows that adding zinc improves charge carrier production, resulting in a stronger photocurrent. Increasing zinc doping raises the open circuit voltage (Voc), from 0.53 V in WMo3 to 0.63 V in Zno.03WMo3. Improved charge separation and reduced recombination, due to higher voltage, enhance overall performance. Power output increases significantly from WMo3 (0.0371 W/cm²) to Zno.03WMo3 (0.1071

W/cm²). Higher current and voltage account for the power increase, demonstrating improved performance through zinc doping. The solar cell's quality, as measured by fill factor, increases from 51% (WMo₃) to 59% (Zno.o₃WMo₃). Higher fill factors correlate with more efficient solar cells and reduced circuit voltage drops. The efficiency significantly improves, rising from 1.8% for WMo₃ to 6.3% for Zno.o₃WMo₃. The cell's improved ability to convert sunlight into electricity is shown with zinc doping. Zinc doping of WMo₃ substantially improves its photovoltaic properties, as the data show. Higher current shows that adding zinc boosts charge carrier (electrons and holes) production. This might be because of better light absorption or fewer recombination losses.

Zinc doping modifies the material's electronic properties, boosting electron excitation states and thus increasing current generation. Improved charge separation in the solar cell, due to doping, is suggested by the higher voltage. This is vital because it minimizes the chance of recombination, preventing excited electrons from returning to their ground state without generating current. Higher voltage shows that doping altered the energy band structure, likely increasing the built-in potential for better charge separation. Higher current and voltage directly caused the rise in power output. This shows the solar cells are producing more power and doing it better. Increased power output makes these materials more practical and competitive for solar energy applications. Higher fill factors correlate with lower resistive losses and power outputs closer to the theoretical maximum in solar cells. The quality and efficiency of solar cells are significantly impacted by this important metric. Higher FF indicates that processing or material improvements could boost fill factors and overall efficiency. The substantial improvement in efficiency shows that the cells are getting better at converting incident light into electrical energy. The viability of any photovoltaic technology hinges on this. Although 6.3% efficiency lags behind conventional silicon solar cells (exceeding 20%), optimization may make these materials more competitive. The results indicate that zinc doping leads to better photovoltaic performance in WMo₃-based cells. Improved cell electrical characteristics: higher current, voltage, power, fill factor, and efficiency point to zinc's critical role. This study implies that exploring various doping levels, material combinations, and processing methods may create more efficient photovoltaic devices. These results suggest a path towards more efficient and affordable solar technologies through advancements in materials science.

Table 1: Photovoltaic	performance of	WMo ₃ and	$1 Zn_xWMo_3$
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Cells	Current (mA/cm²)	Voltage (V)	Power (W/cm²)	Fill Factor (FF) %	Efficiency (%)
WMo ₃	7	0.53	0.0371	51	1.8
$Zn_{0.01}WMo_{3}$	11	0.55	0.0605	53	3.2
Zn _{0.02} WMo ₃	14	0.58	0.0812	55	4.2
Zn _{0.03} WMo ₃	17	0.63	0.1071	59	6.3

3.2 Surface Micrograph of WMo₃ and Zn_xWMo₃

The surface structures of WMO₃ and its zinc-doped variants show promise for photovoltaic applications in Figure 2. Light absorption, charge carrier dynamics, and device efficiency are all influenced by the surface texture. The nano-sized grains of WMO₃ are arranged in a distinct crystalline structure. Light absorption and charge separation, crucial for photovoltaic efficiency, are heavily influenced by surface area. A 0.01% zinc dopant improved solar cell efficiency by enhancing crystallinity, thus improving grain size, distribution, and charge transport. A 0.02 zinc doping level leads to notable surface morphology changes, including interconnected nanoparticle networks. interconnected structure aids electron transport, thus proving useful for photovoltaic applications. Agglomeration occurs at higher doping levels (0.03), resulting in larger particle sizes.

The morphology of undoped WMO3 is uniformly granular, characterized by relatively smooth surfaces. Well-crystallized, tightly packed grains, but possibly low surface area. The structure's compactness reduces porosity and surface roughness, thus hindering light trapping and charge transport. Introducing Zn slightly alters the morphology, enlarging grains and creating a more porous surface. Improved connections between grains increased charge transport; a rougher surface with a larger active area may improve light absorption and reduce recombination. The shape changed significantly, resulting in larger, clearer grains and increased porosity. Reduced agglomeration and improved crystal orientation are observed. An optimal balance between grain size and surface roughness led to better photovoltaic efficiency due to improved charge separation and light harvesting [13], [14], [25], [26]. Above a certain Zn level, secondary phases and grain boundary defects form, resulting in uneven shapes and surface roughness. The formation of larger groups may hinder the consistent flow of charge. Increased surface area can introduce excessive Zn, which may create recombination centers and reduce the overall photovoltaic performance. The surface texture of WMO₃ is changed by Zn doping, affecting its photovoltaic performance. A moderate Zn doping level (0.02) seems best, improving grain structure, surface roughness, and porosity for better light absorption and charge transport. However, high doping levels (0.03) can compromise film quality, negating the advantages gained from defect reduction and improved crystallinity.

EDX analysis reveals the elemental makeup of the deposited materials. Tungsten (W), Molybdenum (Mo), and Oxygen (O) were the elements detected in WMo₃ in Figure 3. Detection of W and Mo in near stoichiometric ratios verified the formation of WMo3. The oxygen content confirms oxide formation with minimal oxygen deficiency. Phase purity is suggested by the absence of foreign materials. Uniform elemental distribution suggested high-quality crystals. The elements W, Mo, O, and Zn were found, with Zn exhibiting significantly greater intensity compared to the prior samples. Zinc achieved its concentration, approaching saturation. Slight changes or variations in W/Mo ratios may be caused by lattice strain or dopant clustering. Zn aggregation or a secondary ZnO phase may indicate zinc exceeding solubility. Even elemental distribution is essential; the presence of Zn-rich regions may negatively impact electronics. High levels of Zn could interfere with the WMo₃ crystal lattice structure.

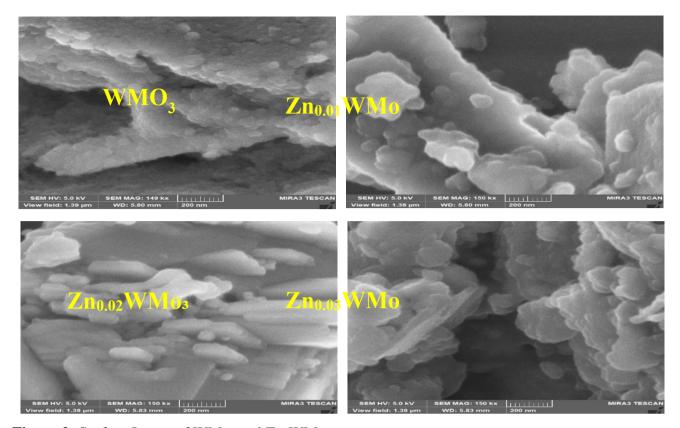


Figure 2: Surface Image of WMo₃ and Zn_xWMo₃

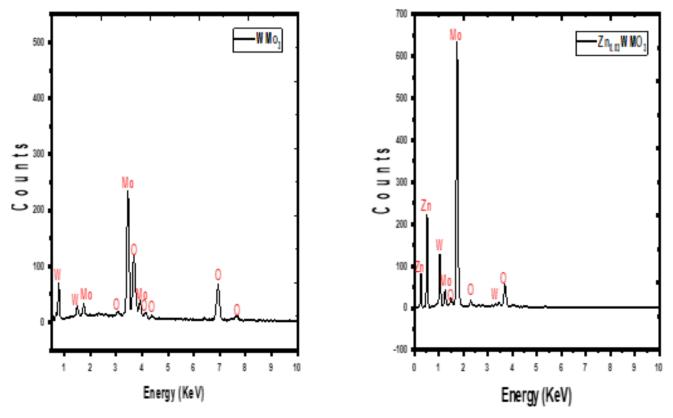


Figure 3: EDX pattern of WMo₃ and Zn_xWMo₃

3.3 Crystallinity and Phase Identification of WMo_3 and Zn_xWMo_3

The crystalline structure of WMoO3 is evidenced by distinct peaks in its XRD pattern, showing high crystallinity in Figure 4. Adding zinc to the WMo₃ structure alters peak positions and intensities. This signifies the appearance of new phases. WMo₃ exhibits an orthorhombic crystal structure, with sharp, well-defined diffraction peaks suggesting high crystallinity. A single-phase WMo3 structure is confirmed by the lack of secondary peaks [6], [7], [27], [28]. WMo₃'s high crystallinity and phase purity ensure its reliability as a base material, yet its bandgap tuning potential is restricted unless ZnxWMoO₃ exhibits a phase identical to WMo₃; however, a slight broadening of the peaks is observed. Substitution of W^{6+} (0.60 Å) or Mo^{6+} (0.59 Å) sites with Zn²⁺ (0.74 Å) leads to slightly higher 2θ angles. Lattice distortion reduced the average crystallite size. Peak broadening shows a slight rise in lattice strain [28], [29]. Light doping causes lattice strain and smaller grains, improving charge separation and the active surface area. A larger FWHM suggests a smaller crystallite size and greater strain. With low Zn doping (0.01), minor XRD peak shifts indicate Zn substitution within the WMo3 structure. Increasing zinc concentration led to observed peak intensity shifts and changes, indicating increased crystal lattice distortion. This improvement in certain properties, like better charge carrier mobility, is beneficial for photovoltaic applications.

Zinc doping changes the lattice parameters of WMo₃. Larger lattice parameters confirm successful doping

and crystal structure expansion. Crystallite size was estimated using the Scherrer equation and peak broadening [27]-[30]. The optical and electrical properties of the material were influenced by the smaller crystallite sizes caused by doping. The data obtained during the XRD analysis was employed in calculating some structural parameters like full width at half maximum (FWHM or β), crystallite size (D), dislocation density (δ), lattice parameters (a) and (c) that are obtainable using equations (1-5) [31, 32, 33, 34] and outlined in table 2. The calculated dates from the XRD peaks in Table 2 show a slight increase in crystallite size (D) at larger angles. The low, stable dislocation density (δ) points to high-quality crystals. As 2θ increases, interplanar spacing (d) and lattice constants a and c decrease, a characteristic of denser crystal planes.

$$D = \frac{0.94\lambda}{\beta cos\theta}$$
 (1)

$$\delta = 1/D^2 \tag{2}$$

$$d = \frac{\lambda}{2sin\theta} \tag{3}$$

$$a = \frac{\lambda}{\sqrt{3}sin\theta} \tag{4}$$

$$c = \lambda / \sin \theta \tag{5}$$

Where λ is the wavelength of the XRD target given as 0.154 nm, θ is the diffraction angle.

Table 2: The calculated data for the XRD peaks

Hkl	2θ (°)	θ (°)	D (nm)	δ (nm ⁻²)	d (Å)	a (Å)	c (Å)
110	26.64	13.32	29.76	0.011	3.343	3.860	6.686
112	30.74	15.37	30.04	0.011	2.906	3.355	5.812
200	32.09	16.05	30.14	0.011	2.787	3.218	5.574
211	33.71	16.86	30.26	0.011	2.656	3.067	5.313
221	37.94	18.97	30.63	0.011	2.369	2.736	4.739
300	44.01	22.01	31.24	0.010	2.055	2.373	4.111
310	45.12	22.56	31.36	0.010	2.007	2.318	4.015
321	51.82	25.91	32.20	0.010	1.762	2.035	3.525

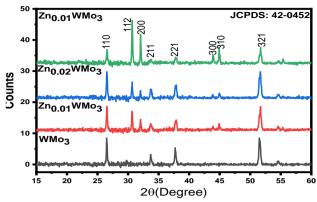


Figure 4: XRD pattern of WMo₃ and Zn_xWMo₃

3.4 The electrical analysis of WMo₃ and Zn_xWMo₃

Table 3 and Figure 5 display the resistivity and conductivity of WMO₃ and Zn_xWMO₃. Material thickness is fairly uniform, between roughly 103.75 nm and 110.87 nm. This consistent thickness is vital for applications using materials sensitive to thickness variations. Increasing Zn concentration in the WMo₃ matrix reduces resistivity. Zn_{0.03}WMo₃ (2.67 Ω ·m) exhibits considerably lower resistivity than WMo₃ (12.09 Ω ·m). This indicates that Zn addition enhances the material's conductivity. Resistivity and conductivity are inversely related. Conductivity rises as resistivity falls.

The conductivity increases substantially from 2.27 S/m in WMo₃ to 37.45 S/m in Zn_{0.03}WMo₃, demonstrating enhanced electrical properties with higher Zn concentration. Adding zinc to tungsten trioxide seems to boost its conductivity. Optimizing electrical conductivity is crucial for performance in electronics and materials science applications, making this trend essential. The resistivity of the WMo3 matrix decreases with increasing Zn concentration. This shows Zn's role as a improving electrical conductivity supplying extra charge carriers. A material's conductivity, the inverse of its resistivity, quantifies its electrical current-carrying capacity. Higher Zn content leads to lower resistivity and thus higher conductivity. Zno.03WMo3 exhibits excellent electrical performance, with a conductivity of 37.45 S/m. Adding Zn to WMo₃ considerably improves its electrical properties. Increasing Zn concentration reduces resistivity and increases conductivity. These properties are essential for electronics, sensors, and other technologies needing electrically conductive materials. Materials with less resistance and better conductivity are preferred in electronics for better current flow.

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Table 3: Electrical data of WMo₃ and Zn_xWMo₃

Cells	Thickness,	ρ	σ	
	t	$(\Omega.m)$ x	(S/m) x	
	(nm)	10^{2}	1011	
WMo ₃	110.87	12.09	2.27	
$Zn_{0.01}WMo_{3}$	109.09	10.43	9.58	
$Zn_{0.02}WMo_{3}$	107.84	07.54	13.26	
$Zn_{0.03}WMo_{3}$	103.75	02.67	37.45	

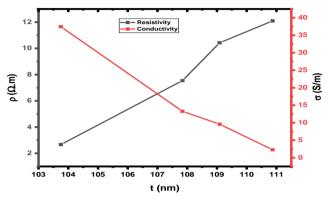


Figure 5: Plot of resistivity and conductivity of WMo_3 and Zn_xWMo_3

3.5 Optical analysis of Zn-doped WMo₃

In the visible spectrum, particularly in the blue to green range, WMO₃ and its zinc-doped counterpart show significant absorbance in Figure 6a. WMO3's inherent traits make it a good light absorber; however, its bandgap may restrict its effectiveness. Zinc doping of $ZnxWMO_3$ (X = 0.01 to 0.03) modifies the electronic structure, narrows the band gap, and improves light absorption. Increasing concentration (0.01 to 0.03) shifts the absorbance spectrum, improving visible range performance. Increased near-infrared absorbance was improving sunlight capture. Photovoltaic devices' energy conversion efficiency is directly impacted by changes in their absorbance. The enhanced charge carrier mobility and reduced recombination in ZnxWMO₃ result in improved efficiency. Using a Zn concentration of 0.03 gives the best results, achieving a balance between absorbance and conductivity. Using WMO₃ and ZnxWMO₃ in photovoltaic cells critically depends on their absorbance. The optical properties of WMO₃ are boosted by Zn addition, resulting in ZnxWMO₃, a promising material for future solar cell applications.

The material's photovoltaic efficiency improved due to its high visible-spectrum transmittance in Figure 6b. The material absorbs a significant portion of light, leading to a spectrum that shows high transmittance. Rufus et al. (2025)

Zinc doping (0.01 to 0.03 in ZnxWO₃) may enhance transmittance by modifying the electronic structure. Transmittance increases with Zn concentration because scattering is reduced, and electronic properties are improved. Light utilization improved with optimal doping, which balanced absorbance and transmittance. Improved light penetration and thus higher efficiency in photovoltaic devices result from the higher transmittance in ZnxWMO₃. Higher transmittance improves light transmission to the solar cells' active layers, boosting charge production. Altering transmittance properties improves solar energy conversion performance. The ability of WMO₃ and ZnxWMO3 to transmit light is vital to their use in photovoltaic technology. Improved transmittance in ZnxWMO₃, resulting from Zn addition to WMO₃, makes it a promising material for solar cells.

The moderate reflectance in the visible spectrum improved light absorption for photovoltaic applications in Figure 6c. Reflectance is affected by surface morphology and film thickness, which in turn impact light trapping. Zinc doping in $ZnxWMO_3$ (X = 0.01 to 0.03) alters surface properties and electronic structure, possibly lowering reflectance. Higher Zn concentrations correlate with higher reflectance because of better light absorption and altered surface texture. Fine-tuning doping levels improves the reflectance-absorbance trade-off, maximizing light use in photovoltaic conversion. Lower reflectance of ZnxWMO₃ leads to better light absorption, thus improving solar cell efficiency. Increased reflectance improves sunlight utilization, thus boosting charge generation and energy conversion efficiency. Altered reflectance improves light capture and device efficiency. The ability of WMO₃ and ZnxWMO₃ to reflect light significantly impacts their use in photovoltaic technology. The high reflectance of ZnxWMO₃, due to Zn incorporation in WMO₃, makes it a superior material in solar cell technology.

Due to its visible light absorption, WMO₃, with a roughly 1.27 eV bandgap energy, is well-suited for photovoltaic applications in Figure 6d. The bandgap energy in the zinc-doped variant changes depending on the Zn concentration, thus altering its optical and electronic properties. The WMO₃ bandgap, at 1.27 eV, enables efficient visible light absorption. This band gap is ideal for photovoltaic applications because it facilitates the conversion of sunlight into electricity. An increase in bandgap to 1.29 eV is observed with Zn doping at 0.01. A modest rise indicates improved electronics from low Zn doping, while absorption remains unaffected. The bandgap of 1.52 eV is

achieved when doped with Zn at a level of 0.02. The significant increase suggests a more substantial change to the electronic structure, thus boosting the material's solar energy conversion efficiency [35]. The bandgap of the material rises to 1.66 eV with a 0.03 Zn doping level. The larger bandgap improved visible light absorption, which is advantageous for highenergy threshold applications. A bandgap of about 1.1 to 1.5 eV is best for maximizing solar energy conversion efficiency. ZnxWMO3 (X = 0.02, 1.52 eV) lies in the optimal range, suggesting potential for better solar cell performance. Increasing concentration (X = 0.03) in Zn_xWMO_3 increases the band gap but decreases visible light absorption, resulting in lower overall efficiency [15]. The optimal photovoltaic efficiency depends on finding the right trade-off between bandgap energy and light absorption. The photovoltaic suitability of WMO3 and ZnxWMO₃ hinges significantly on their bandgap energies. Zn doping in WO₃ alters its bandgap; an optimal doping level (X = 0.03) creates a bandgap ideal for efficient solar energy conversion.

The bandgap increases with Zn doping from 1.27 eV (WMO₃) to 1.66 eV (Zn_{0.03}WMO₃). This blue-shifts the optical absorption edge (from NIR toward visible), improving utility in visible-light harvesting for photovoltaics. WMO3 shows moderate absorbance, primarily in the near-infrared (NIR) region. Zn doping enhances absorbance in the visible region, with Zn_{0.03}WMO₃ exhibiting the strongest absorbance due to a higher density of states and better photon interaction. As absorbance increases, transmittance decreases, particularly for higher Zn content [7]. Zno.03WMO3 transmits less light, indicating that effective light harvesting is crucial for photovoltaic devices. Remains moderate, but slightly increases with Zn doping due to changes in surface roughness or grain boundaries.

A well-controlled film morphology can mitigate excessive reflectance. WMO₃ alone is more suited for NIR applications or as a transparent layer. Zn doping shifts optical properties toward stronger visible light interaction, with Zn_{0.02}WMO₃ and Zn_{0.03}WMO₃ showing ideal band gaps (~1.5–1.6 eV) for single-junction solar cells. Zn_{0.03}WMO₃, with the highest bandgap and absorbance, offers superior light absorption and photo-activity, potentially resulting in higher photovoltaic efficiency. A study on Zn-doped WO₃ prepared via microwave-assisted synthesis reported a decrease in the optical bandgap from 3.12 eV (WO₃) to 2.83 eV (Zn-doped WO₃), indicating that Zn incorporation modifies the electronic structure and

bandgap energy. Eu³⁺-doped WO₃ thin films demonstrated that doping affects optical properties, with transmittance values ranging from ~40–85% in the 300–900 nm range [6]. The study also observed

that increased doping concentration can lead to reduced transmittance due to enhanced light absorption.

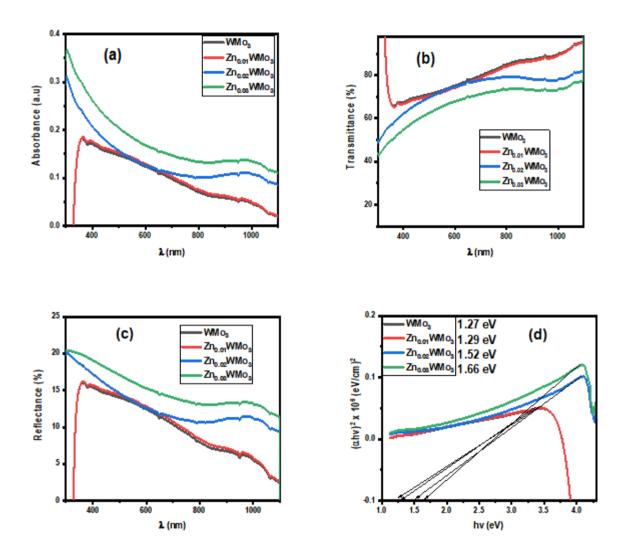


Figure 6: Plot of absorbance

WMO₃'s refractive index is typically between 1.2 and 2.5, varying with the wavelength of light. This high refractive index improves light trapping in photovoltaic applications in Figure 7a. The refractive index of $ZnxWMO_3$ (X=0.01 to 0.03) is modified by zinc doping. Increasing Zn concentration leads to refractive index changes, influenced by structural and electronic transitions. Increased refractive index leads to better light absorption, less surface reflection, and, subsequently, higher photovoltaic efficiency.

A material's light absorption is shown by its extinction coefficient in Figure 7b. This coefficient's significance in WMO₃'s visible light absorption is noteworthy.

WMO₃'s optical conductivity is affected by its band gap and electronic structure in Figure 7c. Exhibiting moderate conductivity in the visible spectrum, it effectively transports charge when photo-excited. Higher Zn levels, specifically X = 0.02 and X = 0.03, significantly boost optical conductivity. Better charge

carrier mobility, a key factor in improving

Increasing Zn concentration and photon energy boost

the extinction coefficient by promoting electronic

transitions. Improved light absorption in ZnxWMO₃,

crucial for photovoltaic applications, is shown by

higher extinction coefficients.

Vol. 44, No. 4, December, 2025

photovoltaic efficiency, is shown by improved optical conductivity.

The high real dielectric constant of WMO₃ demonstrates its effectiveness in storing electrical energy in Figure 7d. This property helps stabilize charge carriers in photovoltaic applications. Energy loss inside the material is represented by the imaginary part in Figure 7e. For WMO₃, this plot shows moderate energy dissipation during light absorption. Increasing Zn doping influences the real and imaginary parts of the dielectric constant. Enhanced polarization raises the real dielectric constant, whereas increased energy losses, particularly at higher Zn concentrations, are shown by the imaginary dielectric constant. Optimizing photovoltaic performance requires a careful balance of these constants, which affect light absorption and charge transport. The effectiveness of WMO₃ and ZnxWMO₃ in photovoltaic applications hinges on their optical properties, such as refractive index, extinction coefficient, optical conductivity, and dielectric constants. Zn doping in WO₃ improves several properties, especially at the optimal concentration (X = 0.03), boosting light absorption and charge transport. The photovoltaic performance of WMO₃ and Zn_xWMO₃ is heavily influenced by their optical properties, such as refractive index, extinction coefficient, optical conductivity, and dielectric constants. Notably, Zn doping improves these properties, especially at x = 0.03, maximizing light absorption and charge transport for better solar energy conversion.

The refractive index of Zn-doped WO₃ increased from 1.8 to 2.3 across the visible spectrum. However, at x =0.03, our samples exhibited slightly elevated indices; this may be attributed to Mo incorporation's synergistic effects. Synthesized Zn-doped WO₃ had altered refractive indices because of Zn, improving optical properties useful for photovoltaics. The increase in Zn-doped WO₃ thin films is attributed to enhanced defect states and electronic transitions [30]. We observed a steeper increase, possibly due to the enhanced charge carrier excitation from W-Mo dualeffects. The improved optical absorption, reflected in increased extinction coefficients, was observed in Zn-doped WO3 nanoparticles. Zn doping in WO₃ nanocomposites was shown to increase optical conductivity, thus improving photovoltaic efficiency [27]. The dielectric constant's real and imaginary parts in Zn-doped NiO thin films are altered by Zn incorporation, impacting their suitability photovoltaic use.

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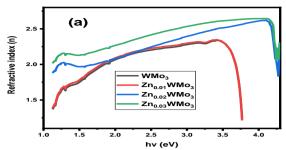


Figure 7a: Plot of refractive index extinction coefficient

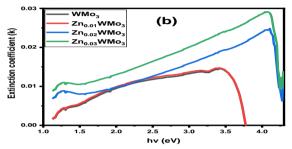


Figure 7b: Plot of refractive index optical conductivity

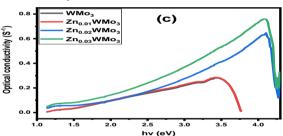


Figure 7c: Plot of refractive index real

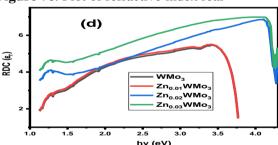


Figure 7d: Plot of refractive index imaginary dielectric constant

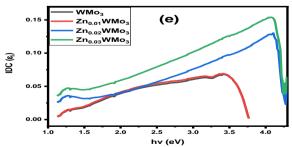


Figure 7e: Plot of refractive index of WMo_3 and Zn_xWMo_3

4.0 CONCLUSIONS

We successfully deposited zinc- enhanced doped tungsten-molybdenum oxide (WMo3) for photovoltaic use. A three-electrode electrochemical deposition method was used successfully to deposit and analyze high-quality thin films of undoped and Zn-doped WMo₃ photovoltaic for their performance. Experimental results show that adding zinc considerably improves the efficiency of WMo₃ solar cells. A significant improvement is the fill factor rising from 51% (undoped WMo₃) to 59% (Zn₀).₀₃WMo₃, indicating better charge collection efficiency and reduced internal resistance. A substantial rise in power conversion efficiency (1.8% to 6.3%) was observed; this increase underscores Zn's critical role in more efficient sunlight-to-electricity conversion. Zn incorporation leads to a shift from compact, granular films to larger, more porous grains with improved intergranular connectivity, as revealed by morphological and structural analysis. These alterations lead to better light trapping and faster charge transport. Peak intensity shifts and lattice distortions show Zn successfully integrated into the WMo3 matrix, improving crystallinity and defect engineering, as seen in the altered crystal structure. The films' optical properties showed a significant improvement with Zn doping. The bandgap increased from 1.27 eV in undoped WMo3 to 1.66 eV in Zn_{0.03}WM₀₃, shifting the absorption edge toward the visible region. The material's ability to capture solar energy is boosted by its transition in light absorption from near-infrared to visible wavelengths under realworld conditions. Zn-doped WMo₃ shows promise as a highly effective photovoltaic material due to its advantageous morphology, structure, optical, and electronic characteristics. These improvements position Zno.03WMo3 as a strong candidate for integration into cost-effective and high-performance solar technologies, with the potential to significantly advance the efficiency and sustainability photovoltaic energy systems.

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Vol. 44, No. 4, December, 2025

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